

General Description

The SYCT is a family of high accuracy galvanically isolated Hall-effect current sensor ICs for $\pm 50\text{A}$ to $\pm 250\text{A}$. Current sensing supports both unidirectional and bidirectional, DC and AC currents. Applied current generates a magnetic field, then converted into a proportional analog voltage. The bandwidth is up to 170kHz and the response time is $3\mu\text{s}$.

The SYCT provides a ratiometric or fixed zero current output for differential measurements. A precise, proportional output voltage is achieved by the high accuracy, good linearity, low temperature drift Hall IC, which is programmed for accuracy at the factory.

The package offers four options, PFF/PSF/PSS/SMT, for easy implementation, which the PFF is the standard package.

The SYCT is suitable for insulation, small size with low heat generation applications, including automotive, industrial, and communications systems.

Features

- 5V single supply
- Wide Hall current sensing range:
 - Bidirectional: $\pm 50 \sim \pm 250\text{A}$
 - Unidirectional: $50 \sim 250\text{A}$
- 170kHz typical bandwidth, response time $0.7\mu\text{s}$
- UL60950-1(ed.2) certified
 - Dielectric Strength Test Voltage = $4800\text{V}_{\text{RMS}}$
 - Working Voltage for Basic Isolation = 700V_{RMS}
 - Working Voltage for Reinforced Isolation = 450V_{RMS}
- Ultralow primary conductor resistance for power loss
- Factory-trimmed for high accuracy
- Package: PFF/PSF/PSS/SMT

Applications

- EV/HEV charger and DC-DC power supply
- Photovoltaic inverter power supply and UPS
- Motor control and frequency converter
- Communication and server power supply

Typical Application

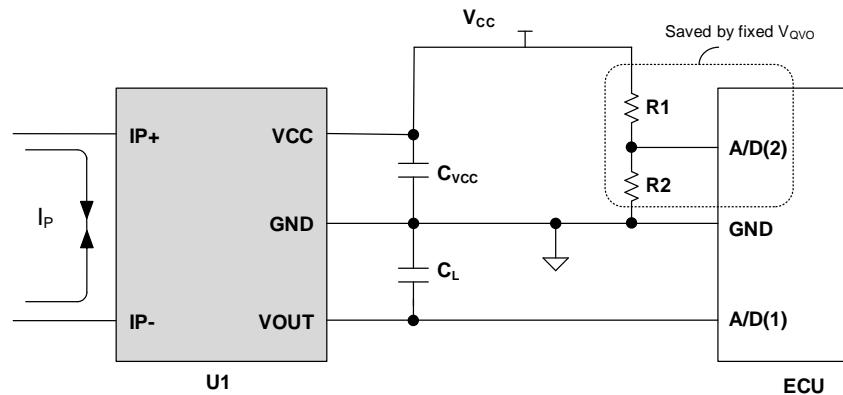
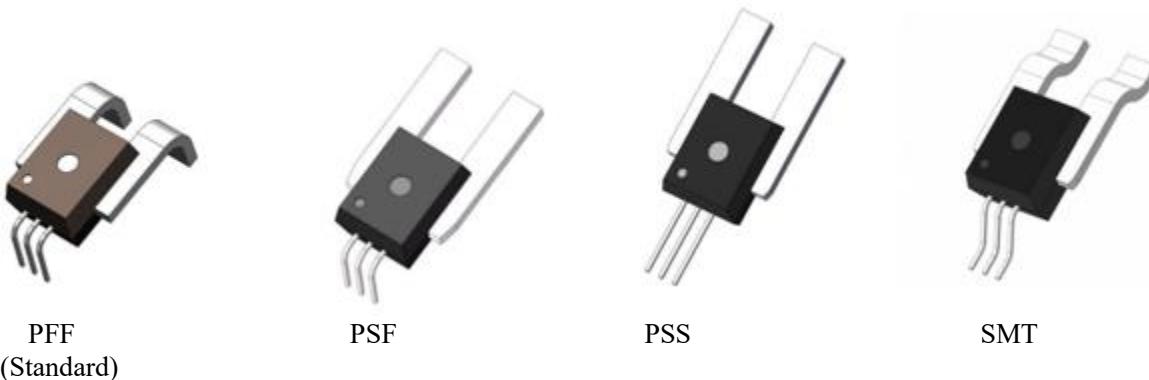


Figure 1. Typical Application Circuit

Package Type

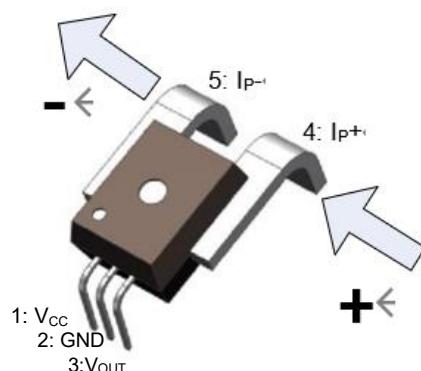


Ordering Information

Please indicate the package type in the suffix when ordering, such as SYCT050BR-PSF.
If the packaging type is not specified, the default is to the standard (PFF) package.

Part Number	Architecture	I _p (A)	Sensitivity(mV/A)	V _{QVO} (V)	T _A (°C)
SYCT050BR	Bidirectional	±50	40	Vcc/2	-40 to 125
SYCT050BF	Bidirectional	±50	40	2.5	-40 to 125
SYCT050UR	Unidirectional	50	80	Vcc/10	-40 to 125
SYCT050UF	Unidirectional	50	80	0.5	-40 to 125
SYCT100BR	Bidirectional	±100	20	Vcc/2	-40 to 125
SYCT100BF	Bidirectional	±100	20	2.5	-40 to 125
SYCT100UR	Unidirectional	100	40	Vcc/10	-40 to 125
SYCT100UF	Unidirectional	100	40	0.5	-40 to 125
SYCT150BR	Bidirectional	±150	13.33	Vcc/2	-40 to 105
SYCT150BF	Bidirectional	±150	13.33	2.5	-40 to 105
SYCT150UR	Unidirectional	150	26.67	Vcc/10	-40 to 105
SYCT200BR	Bidirectional	±200	10	Vcc/2	-40 to 85
SYCT200BF	Bidirectional	±200	10	2.5	-40 to 85
SYCT200UR	Unidirectional	200	20	Vcc/10	-40 to 85
SYCT200UF	Unidirectional	200	20	0.5	-40 to 85
SYCT250BR	Bidirectional	±250	8	Vcc/2	-40 to 85
SYCT250BF	Bidirectional	±250	8	2.5	-40 to 85
SYCT250UR	Unidirectional	250	16	Vcc/10	-40 to 85
SYCT250UF	Unidirectional	250	16	0.5	-40 to 85

Pinout (Top View)



Pin Number	Pin Name	Pin Description
1	V _{CC}	Power supply pin.
2	GND	Ground pin.
3	V _{OUT}	Analog output pin.
4	I _{P+}	Positive terminals for sensing current.
5	I _{P-}	Negative terminals for sensing current.

Absolute Maximum Ratings (Note 1)

Supply Input Voltage -----	-0.3 to 6.5V
Supply Input Current -----	18mA
Output Voltage -----	0.15 to V _{CC} -0.15V
Output Current (Note 2) -----	±40 mA
Ambient Temperature Range -----	-40 to 125°C
Maximum Junction Temperature -----	165°C
Storage Temperature Range -----	-55 to 150°C

Recommended Operating Conditions (Note 3)

Supply Input Voltage -----	4.5 to 5.5V
----------------------------	-------------

Isolation Characteristics

Characteristic	Symbol	Notes	Rating	Unit
Dielectric Strength Test Voltage (Note 4)	V _{ISO}	Agency type-tested for 60 seconds per UL standard 60950-1 (edition 2)	4800	V _{RMS}
Working Voltage for Basic Isolation	V _{WVBI}	For basic (single) isolation per UL standard 60950-1 (edition 2)	990	V _{PK}
			700	V _{RMS}
Working Voltage for Reinforced Isolation	V _{WVRI}	For reinforced (double) isolation per UL standard 60950-1 (edition 2)	636	V _{PK}
			450	V _{RMS}

Electrical Characteristics

($V_{CC} = 5V$, $C_{VCC} = 0.1\mu F$, $T_A = -40$ to $125^\circ C$, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ.	Max	Unit
Supply Voltage	V_{CC}	SYCT-xxxR	4.5	5	5.5	V
		SYCT-xxxF	4.75	5	5.25	
Supply Current	I_{CC}	$R_L \geq 10k\Omega$		13	18	mA
Power on Delay Time	T_{POD}	$T_A=25^\circ C$		80		μs
Zero Current Output Voltage (Note 5)	V_{QVO}	SYCTxxxBR, $T_A = 25^\circ C$		$V_{CC}/2$		V
		SYCTxxxBF, $T_A = 25^\circ C$		2.50		V
		SYCTxxxUR, $T_A = 25^\circ C$		$V_{CC}/10$		V
		SYCTxxxUF, $T_A = 25^\circ C$		0.50		V
Output Voltage Range @ I_P	$V_{OUT}-V_{QVO}$	SYCTxxxBR, $T_A = 25^\circ C$		± 2		V
		SYCTxxxBF, $T_A = 25^\circ C$		± 2		V
		SYCTxxxUR, $T_A = 25^\circ C$		4		V
		SYCTxxxUF, $T_A = 25^\circ C$		4		V
Zero Current Output Ratiometry Error	E_{RAT}		-0.3		0.3	%
Output Load Resistance	R_L	V_{OUT} to V_{CC} or GND	10			$k\Omega$
Output Load Capacitance	C_L	V_{OUT} to GND	6		100	nF
Response Time	t_{RES}	$T_A=25^\circ C$, $C_L=1nF$, I_P step=50% of I_P 90% Input to 90% Output		3		μs
Bandwidth	BW	Small signal -3dB, $C_L=1nF$, $T_A=25^\circ C$	120	170		kHz
DC Output Impedance	R_{OUT}	$T_A = 25^\circ C$		8		Ω

Note 1: Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: Maximum survivable sink or source current on the V_{OUT} pin.

Note 3: The device is not guaranteed to function outside its operating conditions.

Note 4: 60-second test is only for UL test; Tested in production against UL60950-1 2nd Edition.

Note 5: The current sensing ranges (050/100/150/200/250) are represented by xxx.

SYCT050BR and SYCT050BF Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 125°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		-50		50	A
Sensitivity	Sens			40		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 50A		125	250	mA
Offset Current	I _{OE}	T _A = 25°C			0.3	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 125°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT050UR and SYCT050UF Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 125°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		0		50	A
Sensitivity	Sens			80		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 50A		80	150	mA
Offset Current	I _{OE}	T _A = 25°C			0.15	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 125°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT100BR and SYCT100BF Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 125°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		-100		100	A
Sensitivity	Sens			20		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 100A		200	300	mA
Offset Current	I _{OE}	T _A = 25°C			0.5	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 125°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT100UR and SYCT100UF Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 125°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		0		100	A
Sensitivity	Sens			40		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 100A		100	150	mA
Offset Current	I _{OE}	T _A = 25°C			0.25	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 125°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT150BR and SYCT150BF Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 105°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		-150		150	A
Sensitivity	Sens			13.3		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 150A		300	400	mA
Offset Current	I _{OE}	T _A = 25°C			0.75	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 105°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT150UR Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 105°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		0		150	A
Sensitivity	Sens			26.7		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 150A		180	240	mA
Offset Current	I _{OE}	T _A = 25°C			0.45	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 105°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT200BR and SYCT200BF Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 85°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		-200		200	A
Sensitivity	Sens			10		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 200A		400	500	mA
Offset Current	I _{OE}	T _A = 25°C			1	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 85°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT200UR and SYCT200UF Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 85°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		0		200	A
Sensitivity	Sens			20		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 200A		200	250	mA
Offset Current	I _{OE}	T _A = 25°C			0.5	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 85°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT250BR and SYCT250BF Performance Characteristics

(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 85°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		-250		250	A
Sensitivity	Sens			8		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 250A		500	640	mA
Offset Current	I _{OE}	T _A = 25°C			1.25	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 85°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

SYCT250UR and SYCT250UF Performance Characteristics

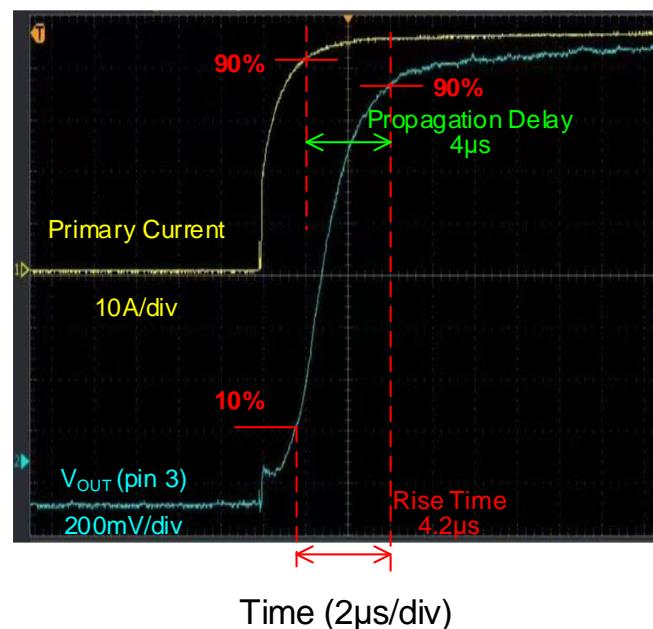
(V_{CC} = 5V, C_{VCC} = 0.1μF, T_A = -40 to 85°C, unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Nominal Performance						
Current Sensing Range	I _P		0		250	A
Sensitivity	Sens			16		mV/A
Accuracy Performance						
Sensitivity Error	E _{SENS}	T _A =25°C	-1		1	%
Voltage Offset Error	V _{OE}	I _P =0A, T _A = 25°C	-4	±3	4	mV
		I _P =0A	-20	±8	20	mV
Magnetic Offset Error	I _{OM}	I _P =0A, T _A = 25°C, after excursion of 250A		250	320	mA
Offset Current	I _{OE}	T _A = 25°C			0.65	A
Linearity Error	E _{LIN}	Full scale of I _P	-1	0.5	1	%
Total Output Error	E _{TOT, H}	Full scale of I _P , T _A = 25 to 85°C	-2		2	%
	E _{TOT, L}	Full scale of I _P , T _A = -40 to 25°C	-2		2	%

Operation Waveform

Typical Propagation Delay and Rise Time

(SYCT, $C_{OUT}=1nF$, Primary Current=45A)



Operation

The SYCT is a family of high accuracy galvanically isolated current sensor ICs. There are various output modes for measuring bidirectional or unidirectional current from 50A to 250A, which output the analog voltage proportional to the AC or DC current. The bandwidth is up to 170kHz.

A precise, proportional output voltage is achieved by the high accuracy Hall IC, which is trimmed for accuracy at the factory.

The package offers four options, PFF/PSF/PSS/SMT, for easy implementation, which the PFF is the standard package.

Application Information

Sensitivity (Sens)

Sensitivity is the slope of the approximate straight line between the output voltage (V_{OUT}) and the input primary current (I_P) within the sensing range. V_{QVO} is the quiescent voltage output.

$$V_{OUT} = V_{QVO} + Sens \times I_P$$

Sensitivity Error (ESENS)

The sensitivity error (E_{SENS}) is the percent difference between the measured sensitivity ($Sens_M$) and the ideal value ($Sens_{TYP}$).

$$E_{SENS} = \frac{Sens_M - Sens_{TYP}}{Sens_{TYP}} \times 100 \text{ (%)}$$

Response Time (tRES)

Response time (t_{RES}) is defined as the time delay from the 90% of input primary current (I_P) to the 90% of the output voltage (V_{OUT}).

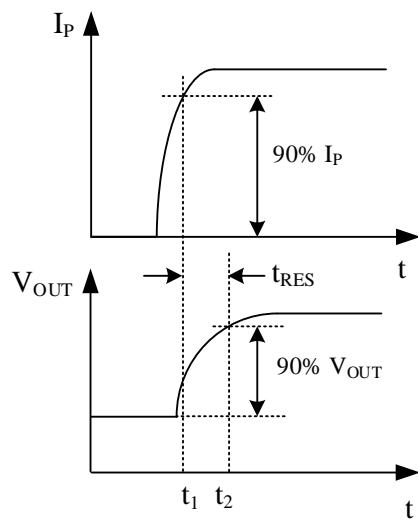


Figure 3. Response Time

Quiescent Voltage Output (V_{QVO})

The V_{QVO} is defined as the output voltage (V_{OUT}) when the primary current (I_P) is zero. It is related to V_{CC} , current direction, and internal logic. The relationship is shown as below, where xxx

represents the sensing range (050/100/150/200/250):

Part Number	V_{QVO}
SYCTxxxBR	$V_{CC}/2$
SYCTxxxBF	2.50V
SYCTxxxUR	$V_{CC}/10$
SYCTxxxUF	0.50V

Voltage Offset Error (V_{OE})

The voltage offset error (V_{OE}) is defined as the deviation of the zero current output voltage from its ideal quiescent value (V_{QVO}), due to nonmagnetic causes.

Zero Current Output Ratiometric Error (ERAT)

When the supply voltage V_{CC} changes from the typical value ($V_{CC,TYP}$) to $V_{CC,MIN} < V_{CC,M} < V_{CC,MAX}$ there will be a certain deviation between the measured zero current output ($V_{QVO,M}$) and its ideal value ($V_{QVO,TYP}$). The relationship is shown as below:

$$E_{RAT} = 1 - \frac{V_{QVO,M}}{V_{CC,M}} \times \frac{V_{CC,TYP}}{V_{QVO,TYP}}$$

Magnetic Offset Error (I_{OM})

The magnetic offset is due to the remnant field of the core material. The magnetic offset error is highest when the primary current approaches zero from the maximum value.

Linearity Error (E_{LIN})

The linearity error (E_{LIN}) is the maximum positive or negative error between the measured output voltage and the ideal value within the sensing range.

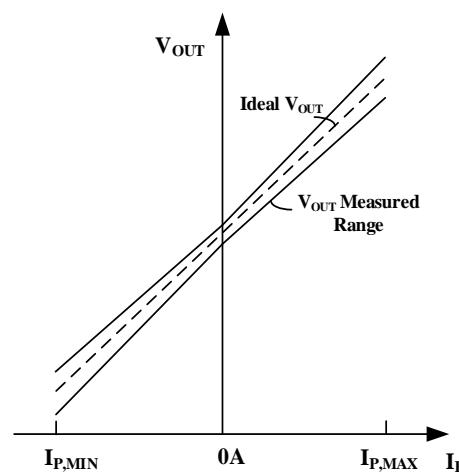


Figure 4. Linearity Error

Total Output Error (E_{TOT})

Total output error (E_{TOT}) is defined as the difference between the ideal output voltage (V_{OUT}) and the actual output voltage (V_{OUT,I_P}), divided by the ideal sensitivity ($Sens$), relative to the primary current (I_P) flowing through the primary conduction path:

$$E_{TOT} = \frac{V_{OUT,IP} - V_{OUT}}{Sens \times I_P}$$

At relatively high current, E_{TOT} will be mostly due to sensitivity errors; but at relatively low current, E_{TOT} will be mostly due to the voltage offset error (V_{OE}). As the primary current (I_P) approaches zero, the E_{TOT} approaches infinity due to the voltage offset error (V_{OE}).

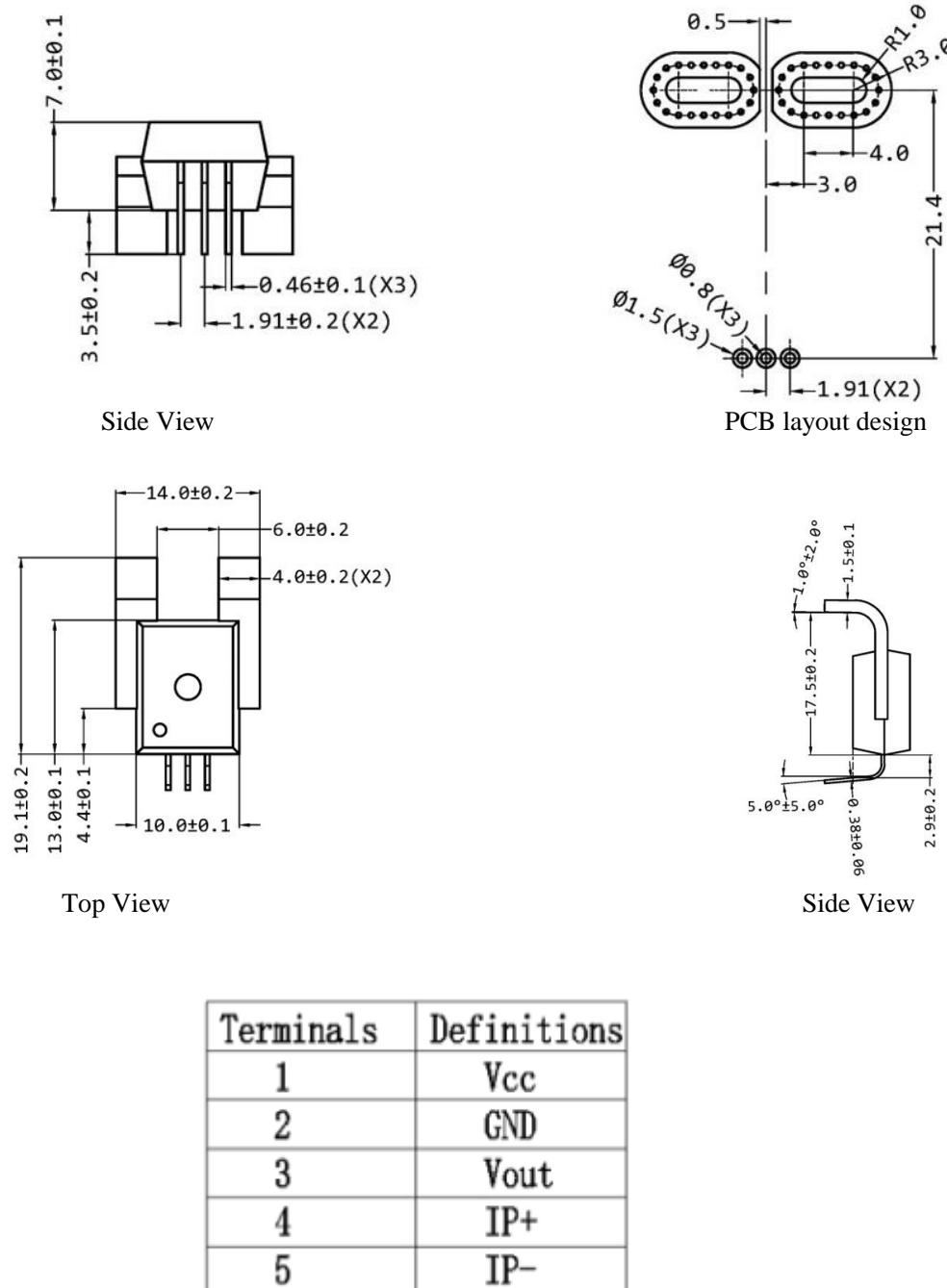
Layout Design

The layout design of the SYCT is relatively simple. For the best performance, the attention should be paid to heat dissipation and traces.

1. It is best practice for the current to approach the IC parallel to the current-carrying pins, and for the current-carrying trace to not creep towards the center of the package.
2. It is best to place Cvcc and C_L close to the IC to achieve better filtering performance.

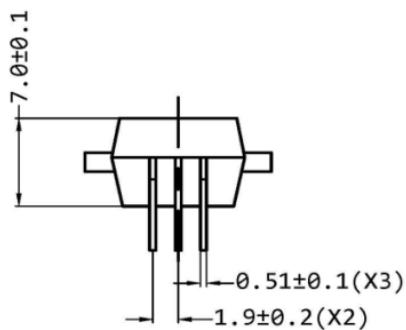
Package outline & PCB Layout Design

Standard (PFF) Package

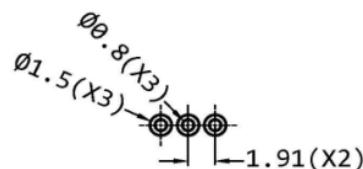


Notes: All dimensions are in millimeters.
All dimensions don't include mold flash & metal burr.

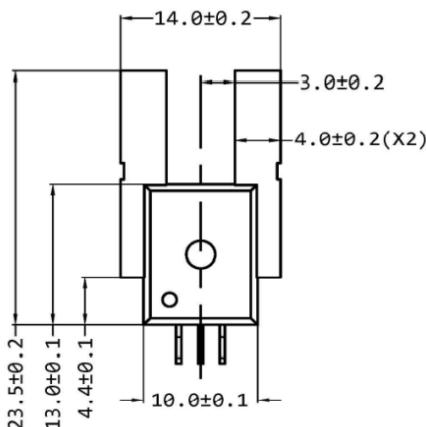
PSF Package



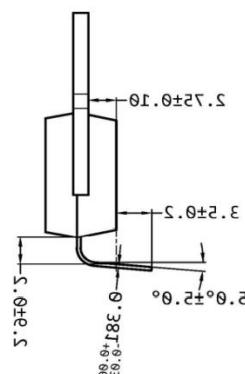
Side View



PCB layout design



Top View

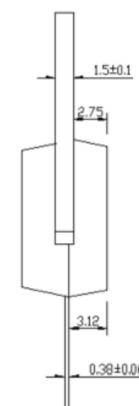
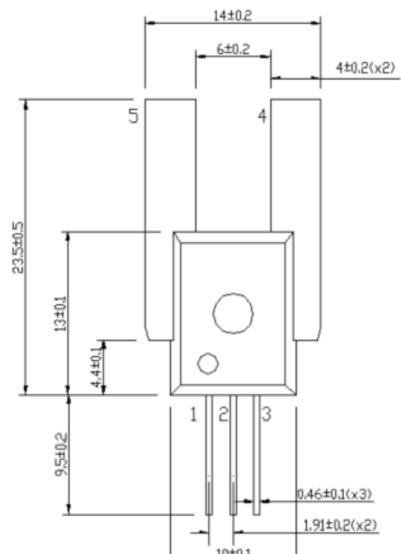
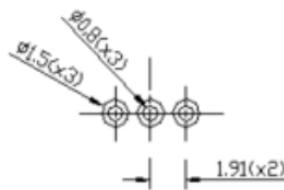
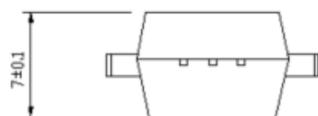


Side View

Terminals	Definitions
1	Vcc
2	GND
3	Vout
4	IP+
5	IP-

Notes: All dimensions are in millimeters.
All dimensions don't include mold flash & metal burrs.

PSS Package



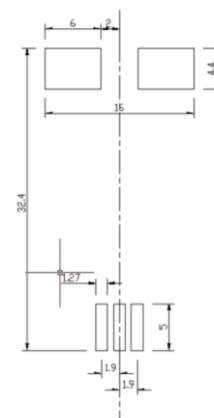
Terminals	Definitions
1	VCC
2	GND
3	VOUT
4	IP+
5	IP-

Notes: All dimensions are in millimeters.
All dimensions don't include mold flash & metal burr.

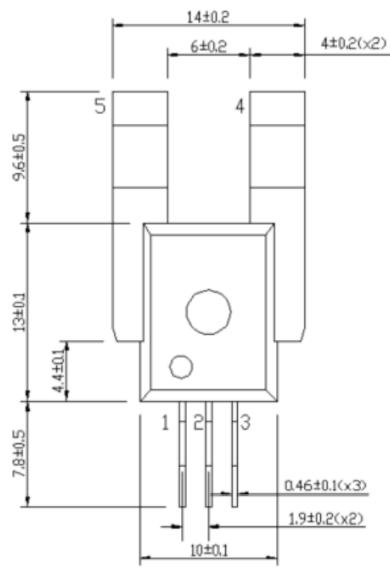
SMT Package



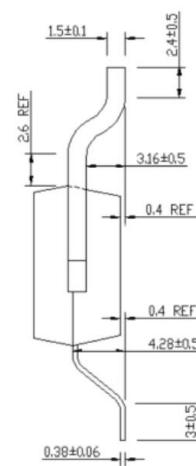
Side View



PCB layout design



Top View



Side View

Terminals	Definitions
1	VCC
2	GND
3	VOUT
4	IP+
5	IP-

Notes: All dimensions are in millimeters.

All dimensions don't include mold flash & metal burr.